



APG015SEKKC-TT
0.45 x 0.25 x 0.2 mm SMD Chip LED Lamp

DESCRIPTIONS

- The Super Bright Orange source color devices are made with AlGaInP on GaAs substrate Light Emitting Diode
- Electrostatic discharge and power surge could damage the LEDs
- It is recommended to use a wrist band or anti-electrostatic glove when handling the LEDs
- All devices, equipments and machineries must be electrically grounded

FEATURES

- 0.45 mm x 0.25 mm SMD LED, 0.2 mm thickness
- Low power consumption
- Wide viewing angle
- Compatible with automatic placement equipment
- Package: 4000 pcs / reel
- Moisture sensitivity level: 2
- Halogen-free
- RoHS compliant

APPLICATIONS

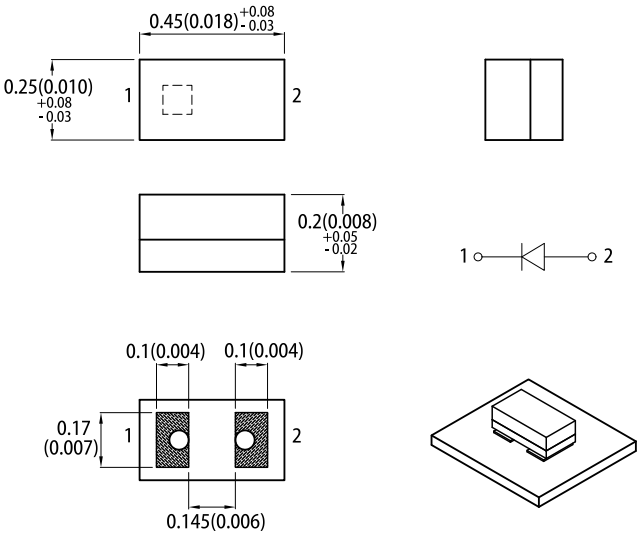
- Backlight
- Status indicator
- Home and smart appliances
- Wearable and portable devices
- Healthcare applications

ATTENTION

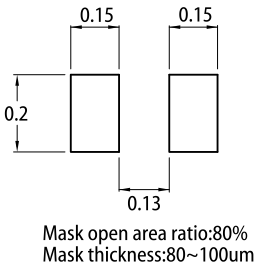
Observe precautions for handling electrostatic discharge sensitive devices



PACKAGE DIMENSIONS



RECOMMENDED SOLDERING PATTERN
(units : mm; tolerance : ± 0.02)



- Notes:
1. All dimensions are in millimeters (inches).
 2. Tolerance is ±0.02(0.001") unless otherwise noted.
 3. The specifications, characteristics and technical data described in the datasheet are subject to change without prior notice.
 4. The device has a single mounting surface. The device must be mounted according to the specifications.

SELECTION GUIDE

Part Number	Emitting Color (Material)	Lens Type	Iv (mcd) @ 10mA ^[2]		Viewing Angle ^[1]
			Min.	Typ.	2θ1/2
APG015SEKKC-TT	Super Bright Orange (AlGaInP)	Water Clear	60	150	140°
			*20	*50	

Notes:
1. θ1/2 is the angle from optical centerline where the luminous intensity is 1/2 of the optical peak value.
2. Luminous intensity / luminous flux: +/-15%.
* Luminous intensity value is traceable to CIE127-2007 standards.

ELECTRICAL / OPTICAL CHARACTERISTICS at T_A=25°C

Parameter	Symbol	Emitting Color	Value		Unit
			Typ.	Max.	
Wavelength at Peak Emission I _F = 10mA	λ _{peak}	Super Bright Orange	611	-	nm
Dominant Wavelength I _F = 10mA	λ _{dom} ^[1]	Super Bright Orange	605	-	nm
Spectral Bandwidth at 50% Φ REL MAX I _F = 10mA	Δλ	Super Bright Orange	17	-	nm
Forward Voltage I _F = 10mA	V _F ^[2]	Super Bright Orange	2.0	2.4	V
Reverse Current (V _R = 5V)	I _R	Super Bright Orange	-	10	μA
Temperature Coefficient of λ _{peak} I _F = 10mA, -10°C ≤ T ≤ 85°C	TC _{λpeak}	Super Bright Orange	0.13	-	nm/°C
Temperature Coefficient of λ _{dom} I _F = 10mA, -10°C ≤ T ≤ 85°C	TC _{λdom}	Super Bright Orange	0.09	-	nm/°C
Temperature Coefficient of V _F I _F = 10mA, -10°C ≤ T ≤ 85°C	TC _V	Super Bright Orange	-2.0	-	mV/°C

- Notes:
- 1. The dominant wavelength (λd) above is the setup value of the sorting machine. (Tolerance λd : ±1nm.)
 - 2. Forward voltage: ±0.1V.
 - 3. Wavelength value is traceable to CIE127-2007 standards.
 - 4. Excess driving current and / or operating temperature higher than recommended conditions may result in severe light degradation or premature failure.

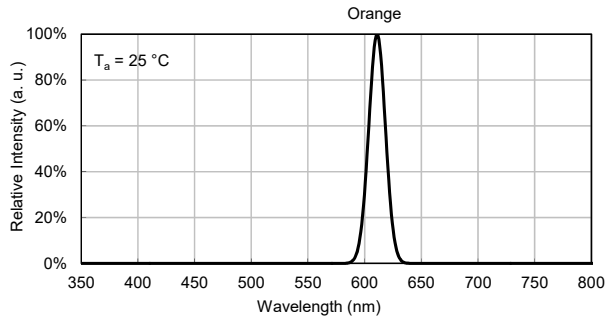
ABSOLUTE MAXIMUM RATINGS at T_A=25°C

Parameter	Symbol	Value	Unit
Power Dissipation	P _D	24	mW
Reverse Voltage	V _R	5	V
Junction Temperature	T _j	115	°C
Operating Temperature	T _{op}	-40 to +85	°C
Storage Temperature	T _{stg}	-40 to +85	°C
DC Forward Current	I _F	10	mA
Peak Forward Current	I _{FP} ^[1]	40	mA
Electrostatic Discharge Threshold (HBM)	-	3000	V
Thermal Resistance (Junction / Ambient)	R _{th JA} ^[2]	670	°C/W
Thermal Resistance (Junction / Solder point)	R _{th JS} ^[2]	490	°C/W

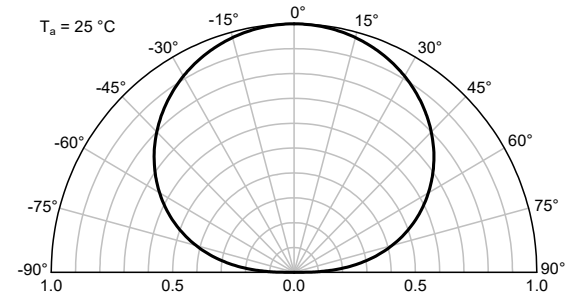
- Notes:
- 1. 1/10 Duty Cycle, 0.1ms Pulse Width.
 - 2. R_{th JA}, R_{th JS} Results from mounting on PC board FR4 (pad size ≥ 16 mm² per pad).
 - 3. Relative humidity levels maintained between 40% and 60% in production area are recommended to avoid the build-up of static electricity – Ref JEDEC/JESD625-A and JEDEC/J-STD-033.

TECHNICAL DATA

RELATIVE INTENSITY vs. WAVELENGTH

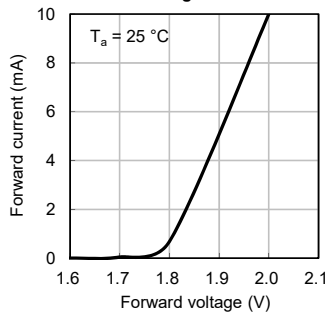


SPATIAL DISTRIBUTION

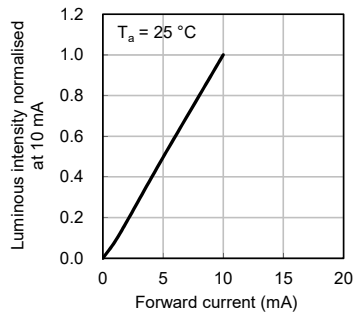


SUPER BRIGHT ORANGE

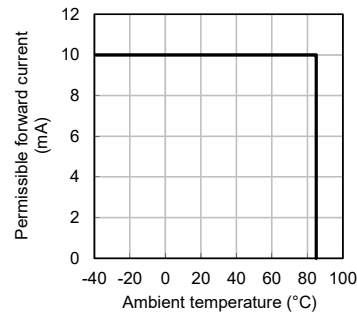
Forward Current vs. Forward Voltage



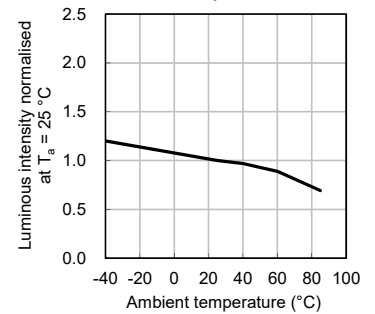
Luminous Intensity vs. Forward Current



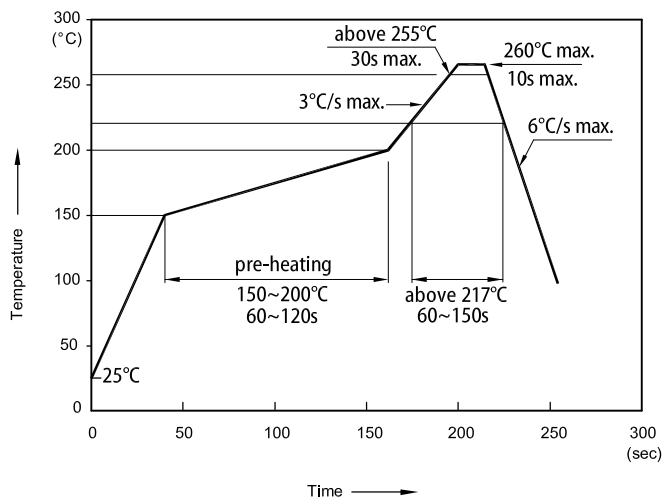
Forward Current Derating Curve



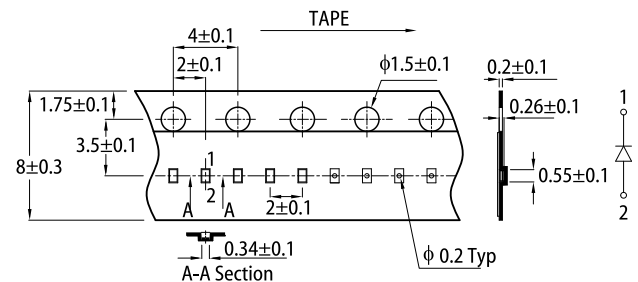
Luminous Intensity vs. Ambient Temperature



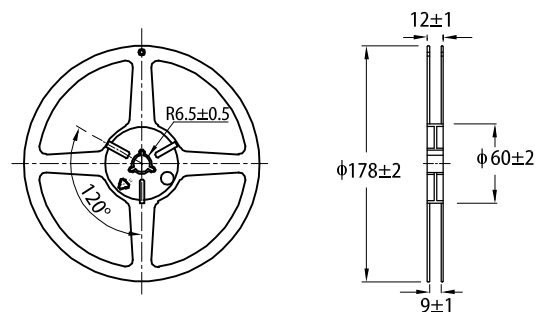
REFLOW SOLDERING PROFILE for LEAD-FREE SMD PROCESS



TAPE SPECIFICATIONS (units : mm)



REEL DIMENSION (units : mm)



- Notes:
1. Don't cause stress to the LEDs while it is exposed to high temperature.
 2. The maximum number of reflow soldering passes is 2 times.
 3. Reflow soldering is recommended. Other soldering methods are not recommended as they might cause damage to the product.

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